#### Nch 600V 25A Power MOSFET

$V_{DSS}$	600V
R <sub>DS(on)</sub> (Max.)	0.182Ω
I <sub>D</sub>	±25A
P <sub>D</sub>	85W

# P<sub>D</sub> 8

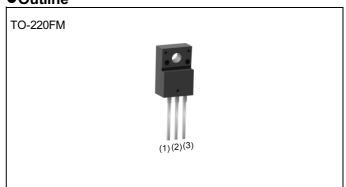
#### Features

- 1) Fast reverse recovery time (trr)
- 2) Low on-resistance
- 3) Fast switching speed
- 4) Drive circuits can be simple
- 5) Pb-free plating; RoHS compliant

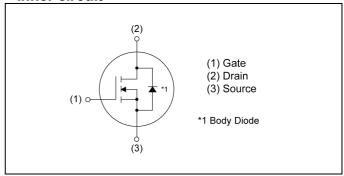
# Application

Switching applications

#### Outline



### •Inner circuit



Packaging specifications

i dende grig e per insulation e				
Packing	Tube			
Packing code	C7 G			
Marking	R6025JNX			
Basic ordering unit (pcs)	2000			

### ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V <sub>DSS</sub>	600	V
Continuous drain current (T <sub>c</sub> = 25°C)	I <sub>D</sub> *1	±25	Α
Pulsed drain current	I <sub>DP</sub> *2	±75	Α
Gate - Source voltage	V <sub>GSS</sub>	±30	V
Avalanche current, single pulse	I <sub>AS</sub> *3	5.0	Α
Avalanche energy, single pulse	E <sub>AS</sub> *3	682	mJ
Power dissipation (T <sub>c</sub> = 25°C)	P <sub>D</sub>	85	W
Junction temperature	T <sub>j</sub>	150	°C
Operating junction and storage temperature range	T <sub>stg</sub>	-55 to +150	°C

1/11

#### ●Thermal resistance

Dougrantou	Cymah al	Values			1.1
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub>	-	-	1.48	°C/W
Thermal resistance, junction - ambient	R <sub>thJA</sub>	-	-	70	°C/W
Soldering temperature, wavesoldering for 10s	T <sub>sold</sub>	-	-	265	°C

# ●Electrical characteristics (T<sub>a</sub> = 25°C)

Parameter	Cymab al	Conditions	Values			Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V$ , $I_D = 1mA$	600	-	-	V
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{DS} = 600V, V_{GS} = 0V$ $T_j = 25^{\circ}C$	-	-	100	μA
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 30V$ , $V_{DS} = 0V$	-	-	±100	nA
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 4.5$ mA	5.0	6.0	7.0	V
Static drain - source on - state resistance	R <sub>DS(on)</sub> *5	$V_{GS} = 15V, I_D = 12.5A$ $T_j = 25^{\circ}C$	-	0.140	0.182	Ω
Gate resistance	$R_{G}$	f = 1MHz, open drain	-	2.0	-	Ω

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Doromotor	Cymah al	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	1900	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 100V	-	115	1	
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	2.0	1	_
Effective output capacitance energy related	C <sub>o(er)</sub> *6	V <sub>GS</sub> = 0V	-	85	1	pF
Effective output capacitance time related	C <sub>o(tr)</sub> *7	V <sub>DS</sub> = 0V to 480V	-	340	1	
Turn - on delay time	t <sub>d(on)</sub> *5	V <sub>DD</sub> ≈ 300V, V <sub>GS</sub> = 15V	-	33	1	
Rise time	<b>t</b> <sub>r</sub> *5	I <sub>D</sub> = 12.5A	1	24	1	no
Turn - off delay time	t <sub>d(off)</sub> *5	$R_L \simeq 24.3\Omega$	-	60	1	ns
Fall time	<b>t</b> <sub>f</sub> *5	$R_G = 10\Omega$	-	18	-	

## ● Gate charge characteristics (T<sub>a</sub> = 25°C)

Darameter	Corrects at	Conditions	Values			l lmit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	$Q_g^{*5}$	V <sub>DD</sub> ≈ 300V	-	57	-	
Gate - Source charge	Q <sub>gs</sub> *5	I <sub>D</sub> = 25A	-	18.5	-	nC
Gate - Drain charge	Q <sub>gd</sub> *5	V <sub>GS</sub> = 15V	-	20.5	-	
Gate plateau voltage	V <sub>(plateau)</sub>	V <sub>DD</sub> ≈ 300V, I <sub>D</sub> = 25A	-	9.8	-	V

<sup>\*1</sup> Limited only by maximum temperature allowed.

<sup>\*2</sup> Pw  $\leq$  10µs, Duty cycle  $\leq$  1%

<sup>\*3</sup> L  $\simeq$  50mH, V<sub>DD</sub> = 50V, R<sub>G</sub> = 25 $\Omega$ , starting T<sub>i</sub> = 25°C

<sup>\*4</sup> Tc=25°C

<sup>\*5</sup> Pulsed

<sup>\*6</sup> Co(er) is a fixed capacitance that gives the same stored energy as Coss while  $V_{DS}$  is rising from 0 to 80%  $V_{DSS}$ .

<sup>\*7</sup> Co(tr) is a fixed capacitance that gives the same charging time as Coss while  $V_{DS}$  is rising from 0 to 80%  $V_{DSS}$ .

# ● Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Values			Unit	
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic	
Source current	I <sub>S</sub> *1	T <sub>C</sub> = 25°C	1	-	25	Α	
Pulsed source current	I <sub>SP</sub> *2	1C - 23 C	1	-	75	Α	
Source-Drain voltage	V <sub>SD</sub> *5	$V_{GS} = 0V, I_{S} = 25A$	-	-	1.7	V	
Reverse recovery time	<b>t</b> <sub>rr</sub> *5		-	90	-	ns	
Reverse recovery charge	Q <sub>rr</sub> *5	I <sub>S</sub> = 25A di/dt = 100A/µs	-	350	-	nC	
Peak reverse recovery current	I <sub>rr</sub> *5		-	8.0	-	Α	

#### Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

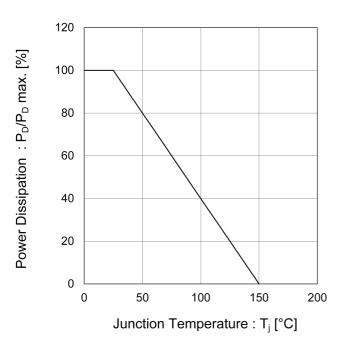


Fig.2 Drain Current Derating Curve vs. Junction Temperature

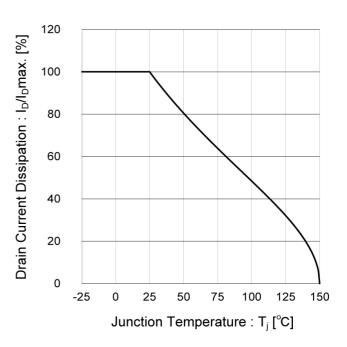


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

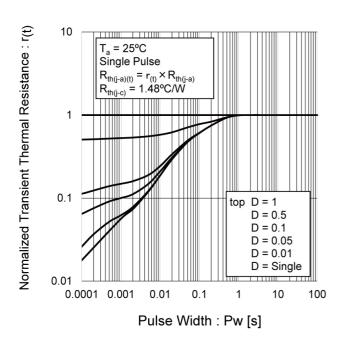
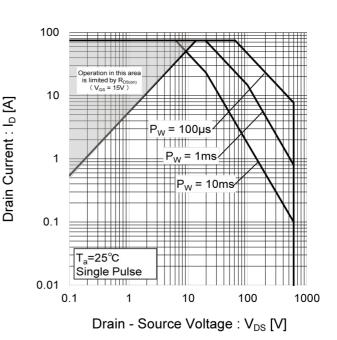


Fig.4 Maximum Safe Operating Area



5/11

#### • Electrical characteristic curves

Fig.5 Avalanche Energy Derating
Curve vs. Junction Temperature

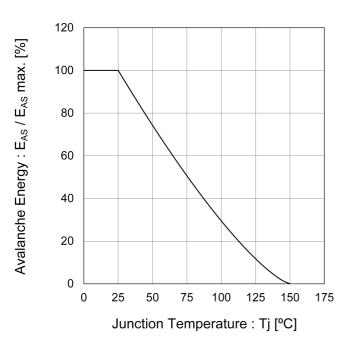


Fig.6 Normalized Breakdown Voltage vs. Junction Temperature

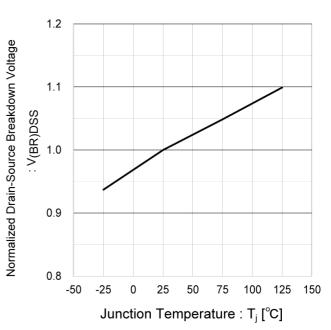


Fig.7 Typical Output Characteristics(I)

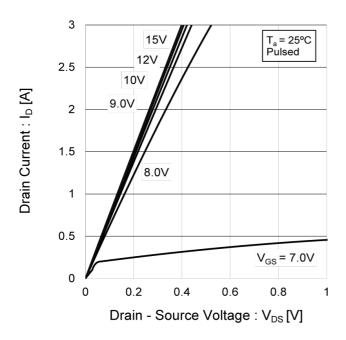
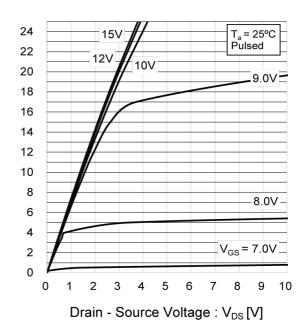


Fig.8 Typical Output Characteristics(II)



Drain Current : I<sub>D</sub> [A]

#### Electrical characteristic curves

Fig.9 Typical Transfer Characteristics

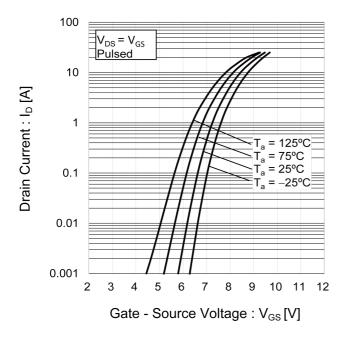


Fig.10 Normalized Gate Threshold .

Voltage vs Junction Temperature

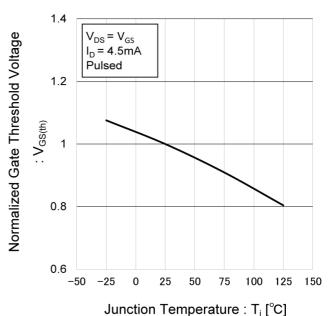


Fig.11 Static Drain - Source On - State Resistance vs. Gate Source Voltage

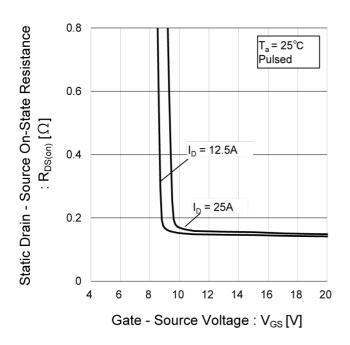
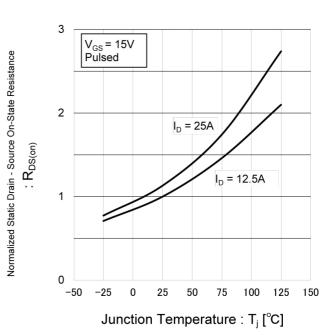


Fig.12 Normalized Static Drain - Source On - State Resistance vs. Junction Temperature



#### • Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Drain Current(I)

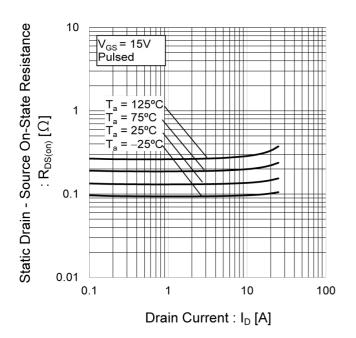


Fig.14 Typical Capacitance vs.
Drain - Source Voltage

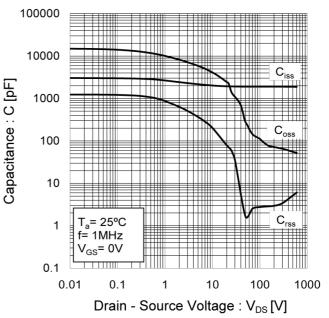


Fig.15 Typical Coss Stored Energy

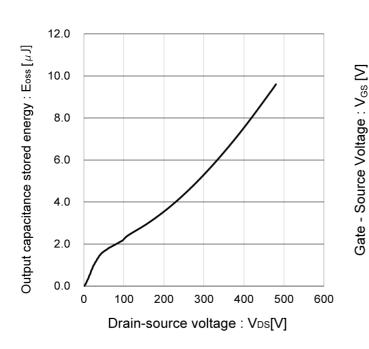
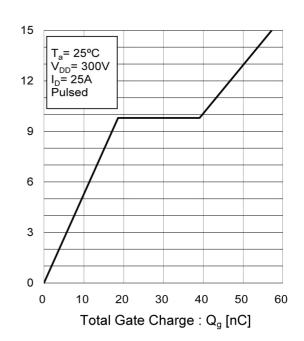
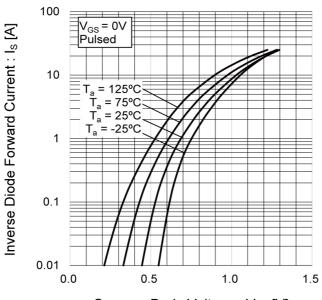


Fig.16 Dynamic Input Characteristics



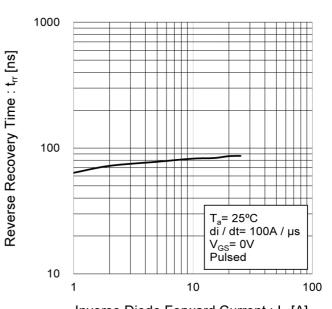
#### • Electrical characteristic curves

Fig.17 Inverse Diode Forward Current vs. Source - Drain Voltage



Source - Drain Voltage : V<sub>SD</sub> [V]

Fig.18 Reverse Recovery Time vs.
Inverse Diode Forward Current



Inverse Diode Forward Current : I<sub>S</sub> [A]

#### Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

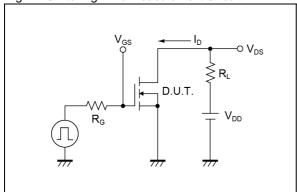


Fig.2-1 Gate Charge Measurement Circuit

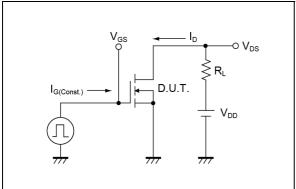


Fig.3-1 Avalanche Measurement Circuit

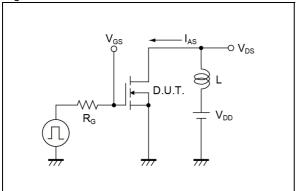


Fig.4-1 Diode Recovery Measurement Circuit

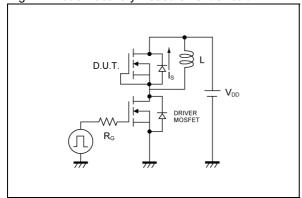


Fig.1-2 Switching Waveforms

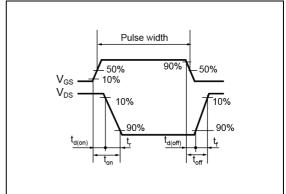


Fig.2-2 Gate Charge Waveform

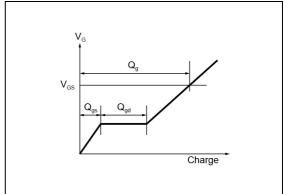


Fig.3-2 Avalanche Waveform

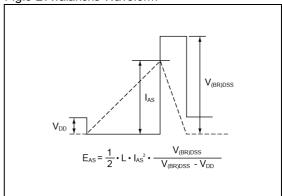
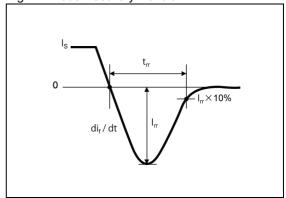
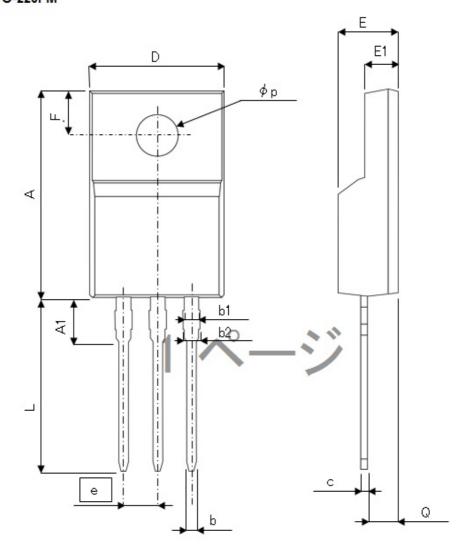


Fig.4-2 Diode Recovery Waveform



### Dimensions

TO-220FM



DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	15.67	16.27	0.617	0.641
A1	3.03	3.43	0.119	0.135
Ь	0.70	0.95	0.028	0.037
ь1	1.00	1.40	0.039	0.055
ь2	1.10	1.50	0.043	0.059
С	0.45	0.65	0.018	0.026
D	9.90	10.30	0.390	0.406
E	4.60	5.00	0.181	0.197
E1	2.44	2.74	0.096	0.108
е	2.	54	0.1	00
F	3.10	3.50	0.122	0.138
L	12.6	13.6	0.496	0.535
р	2.98	3.38	0.117	0.133
Q	2.25	3.25	0.089	0.128

Dimension in mm / inches



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CLASSⅢ	CLASSⅢ	CLASS II b	CL ACCTI
CLASSIV	CLASSIII	CLASSⅢ	CLASSIII

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  - [h] Use of the Products in places subject to dew condensation
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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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For details, please refer to ROHM Mounting specification

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
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- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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